

EAMCET CODE: INDI









(Formerly RVR Institute of Engineering & Technology )

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JNTUH CODE: X3

## **COURSE FILE**

ON

## APPLIED PHYSICS LB

**Course Code - AP205BS** 

IB. Tech Semester-II

A.Y. 2022-2023

Prepared by

Mr. M JANAIAH

**Asst. Professor** 

Head of the Department Department of H&S

SRI INDU INSTITUTE OF ENGG & TECH beriguda(M) Ibrahimoatham (M) R.R. Dist-501 516 PRINCIPAL

Sri Indu Institute of Engineering & Tech Sheriguda(Vill), Ibrahimpatnam R.R. Dist. Telangana-501 510.



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JNTUH CODE: X3

Name of the Physical	
laboratory:	APPLIED PHYSICS LAB
Course code	AP205BS
Room No	B-201 & D-106
Name of the lab in charge	B. SANTHI
Name of the faculty in charge	M. JANAIAH

### **Index of Lab File**

S. No.	Name of the content
1	Institute vision and mission
2	Programme outcomes
3	Course Syllabus with Structure
4	Course Outcomes (CO) and CO-PO mapping
5	List of experiments and their CO, PO mapping
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8	Schedule of end practical examinations
9	List of examiners
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12	Physical lab floor plan with area in Sq.m
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**JNTUH CODE: X3** 

### INSTITUTE VISION & MISSION

### Vision:

To become a premier institute of academic excellence by providing the world class education that transforms individuals into high intellectuals, by evolving them as empathetic and responsible citizens through continuous improvement.

### Mission:

- > IM1: To offer outcome-based education and enhancement of technical and practical skills.
- ➤ IM2: To Continuous assess of teaching-learning process through institute-industry collaboration.
- ➤ IM3: To be a Centre of excellence for innovative and emerging fields in technology development with state-of-art facilities to faculty and students' fraternity.
- ➤ **IM4:** To Create an enterprising environment to ensure culture, ethics and social responsibility among the stakeholde

Head of the Department Department of H&S

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PRINCIPAL

Sri Indu Institute of Engineering & Tech Sheriguda(Vill), Ibrahimpatnam R.R. Dist. Telangana-501 510.

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### **PROGRAM OUTCOMES**

PO1: ENGINEERING KNOWLEDGE: Apply the knowledge of mathematics, science, engineering fundamentals, and an engineering specialization to the solution of complex engineering problems.

PO2: PROBLEM ANALYSIS: Identify, formulate, research literature, and analyze complex engineering problems reaching substantiated conclusions using first principles of mathematics, natural sciences, and engineering sciences.

PO3: DESIGN/DEVELOPMENT OF SOLUTIONS: Design solutions for complex engineering problems and design system components or processes that meet the specified needs with appropriate consideration for the public health and safety, and the cultural, societal, and environmental considerations.

PO4: CONDUCT INVESTIGATIONS OF COMPLEX PROBLEMS: Use researchbased knowledge and research methods including design of experiments, analysis and interpretation of data, and synthesis of the information to provide valid conclusions.

PO5: MODERN TOOL USAGE: Create, select, and apply appropriate techniques, resources, and modern engineering and IT tools including prediction and modelling to complex engineering activities with an understanding of the limitations.

PO6: THE ENGINEER AND SOCIETY: Apply reasoning informed by the contextual knowledge to associate, health, safety, legal and cultural issues and the consequent responsibilities relevant to the professional engineering practice.

PO7: ENVIRONMENT AND SUSTAINABILITY: Understand the impact of the professional engineering solutions in societal and environmental contexts, and demonstrate the knowledge of, and need for sustainable development.

PO8: ETHICS: Apply ethical principles and commit to professional ethics and responsibilities and norms of the engineering practice.

PO9: INDIVIDUAL AND TEAM WORK: Function effectively as an individual, and as a member or leader in diverse teams, and in multidisciplinary settings.

PO10: COMMUNICATION: Communicate effectively on complex engineering activities with the engineering community and with society at large, such as, being able to comprehend and write effective reports and design documentation, make effective presentations, give and receive clear instructions.

PO11: PROJECT MANAGEMENT AND FINANCE: Demonstrate knowledge and understanding of the engineering and management principles and apply these to one's own work, as a member and leader in a team, to manage projects and in multidisciplinary environments.

PO12: LIFE-LONG LEARNING: Recognize the need for, and have the preparation and ability to engage in independent and life-long learning in the broadest context of technological change

> Head of the Departmen Department of H&S SRI INDU INSTITUTE OF ENGG & TECH

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**Class: DATA SCIENCE** 

Semester: II W.E.F-03-04-2023

**LH: D-208** 

	I 9:40- 10:30	II 10:30 - 11:20	III 11:20- 12:10	12:10- 12.45	IV 12.45- 1.35	V 1.35- 2.25	VI 2.25- 3.15	VII 3.15-4.00
MON		PYTHON LAI	В		AP	ODE	EDC	LIBRARY
TUE		ITWS/EWS LA	LU	AP	EDC	ENG	ODE(T) /AP(T)	
WED	ODE	AP	ES	N C	ITW	S/EWS LA	AB	PYTHON LAB(T)/ EWS(T)
THU	ODE	ENG	EDC	н	ODE	EDC	AP	AP(T)/ODE(T)
FRI	AP	ENG	EDC		AP/ELCS LAB			EWS(T)/ PYTHONLAB(7
SAT	ENG	ODE	ES		AP/ELCS LAB			ES

Course Code	Course Name	Name of the Faculty	Course Code	Course Name	Name of the Faculty
MA201BS	ODE-Ordinary Differential Equations & Vector Calculus	CH.SARITHA	AP205BS	APLAB-Applied Phyics Laboratory	B.SANTHI/M.MAN ISHA/M.JANAIAH /P.SRINIVASACH ARY
AP202BS	AP-Applied Physics	Dr.B.NAGALAKSHMI	CS201ES	Python Programming Laboratory	P.BALU/M.TEJAS WI
EN204HS	ENG- English for Skill Enhancement	S.SWAPNA	EN207HS	ELCS LAB-English Language and Communication Skills Laboratory	E.PRARTHANA/S. SWAPNA
EC201ES	EDC-Electronics Devices and Circuits	P.SUMANA	CS203ES	ITWS-IT Workshop	B.RAJITHA/N.KEE RTHI CHANDANA
ME202ES	EWS-Engineering Workshop	W.MARUTHI/B.SRIN U NAIK	MC201ES	ES-Environmental Science	G.VIJAY

Class In-Charge

Time Table Coordinator

Head of The Department

Sri Indu Institute of Engg. & Tech Main Road, Sheriguda(V) Ibrahimpatnam(M), R.R. Dist. Telangana-501 510

# B.Tech. in COMPUTER SCIENCE AND ENGINEERING (DATA SCIFNCE) COURSE STRUCTURE, I YEAR SYLLABUS

(BR22 Regulations)

Applicable from Academic Year: 2022-23 Batch

### I Year II Semester

S. No.	Course Code	Course Title	L	T	P	Credits
1.	MA101BS	Matrices and Calculus	3	1	0	4
2.	CH103BS	Engineering Chemistry	3	1	0	4
3.	CS103ES	Programming for Problem Solving	3	0	0	3
4.	EE101ES	Basic Electrical Engineering	2	0	0	2
5.	ME101ES	Computer Aided Engineering Graphics	1	0	4	3
6.	CS106ES	Elements of Computer Science & Engineering	0	0	2	1
7.	CH106BS	Engineering Chemistry Laboratory	0	0	2	1
8.	CS107ES	Programming for Problem Solving Laboratory	0	0	2	1
9.	EE102ES	Basic Electrical Engineering Laboratory	0	0	2	1
		Induction Program				
		Total	12	2	12	20

### I Year II Semester

S. No.	Course Code	Course	L	Т	P	Credits
1.	MA201BS	Ordinary Differential Equations and Vector Calculus	3	1	0	4
2.	AP202BS	Applied Physics	3	1	0	4
3.	ME202ES	Engineering Workshop	0	1	3	2.5
4.	EN204HS	English for Skill Enhancement	2	0	0	2
5.	EC201ES	Electronic Devices and Circuits	2	0	0	2
6.	AP205BS	Applied Physics Laboratory	0	0	3	1.5
7.	CS201ES	Python Programming Laboratory	0	1	2	2
8.	EN207HS	English Language and Communication Skills Laboratory	0	0	2	1
9.	CS203ES	IT Workshop	0	0	2	1
10.	*MC201ES	Environmental Science	3	0	0	0
		Total	13	4	12	20

### APPLIED PHYSICS LABORATORY

(Course Code: AP205BS)

### B.Tech. I Year II Sem.

L T P C 0 0 3 1.5

**Course Objectives:** The objectives of this course for the student to

- 1. Capable of handling instruments related to the Hall effect and photoelectric effect experiments and their measurements.
- 2. Understand the characteristics of various devices such as PN junction diode, Zener diode, BJT,LED, solar cell, lasers and optical fiber and measurement of energy gap and Resistivity of semiconductor materials.
- 3. Able to measure the characteristics of dielectric constant of a given material.
- 4. Study the behavior of B-H curve of ferromagnetic materials.
- 5. Understanding the method of least squares fitting.

### **Course Outcomes:** The students will be able to:

- 1. Know the determination of the Planck's constant using Photo electric effect and identify the material whether it is n-type or p-type by Hall experiment.
- 2. Appreciate quantum physics in semiconductor devices and microelectronics.
- 3. Gain the knowledge of applications of dielectric constant.
- 4. Understand the variation of magnetic field and behavior of hysteresis curve.
- 5. Carried out data analysis.

### LIST OF EXPERIMENTS:

- 1. Determination of work function and Planck's constant using photoelectric effect.
- 2. Determination of Hall co-efficient and carrier concentration of a given semiconductor.
- 3. Characteristics of series and parallel LCR circuits.
- 4. V-I characteristics of a p-n junction diode and Zener diode
- 5. Input and output characteristics of BJT (CE, CB & CC configurations)
- 6. a) V-I and L-I characteristics of light emitting diode (LED)
  - b) V-I Characteristics of solar cell
- 7. Determination of Energy gap of a semiconductor.
- 8. Determination of the resistivity of semiconductor by two probe method.
- 9. Study B-H curve of a magnetic material.
- 10. Determination of dielectric constant of a given material
- 11. a) Determination of the beam divergence of the given LASER beam
  - b) Determination of Acceptance Angle and Numerical Aperture of an optical fiber.
- 12. Understanding the method of least squares torsional pendulum as an example.

*Note:* Any 8 experiments are to be performed.

### **REFERENCE BOOK:**

S. Balasubramanian, M.N. Srinivasan "A Text book of Practical Physics"- S Chand Publishers, 2017.



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A. Y: 2022-23 SEMESTER: II CLASS:CSE(DATA SCIENCE)

### **Course Outcomes**

After completing this course, the student will be able to:

C126.1	Demonstrate Photoelectric Effect and Determine the work Function and
	planks constant (Understanding)L2
C126.2	Analyzing the properties of semiconductor materials. (Analyzing)L4
C126.3	Illustrate the characteristics of semiconductors devices ( $Understanding$ ) $L2$
C126.4	Construct LCR and RC circuit and evaluate their characteristics
	(Applying)L3
C126.5	Find the properties of Laser and Optical fibre (Remembering) L1
C126.6	Explain the properties of least squares, Dielectric and magnetic materials.
	(Evaluating) L5

### **Mapping of course outcomes with program outcomes:**

High -3 Medium -2 Low-1

PO/CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO 10	PO 11	PO 12	PSO 1	PSO 2
C126.1	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.2	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.3	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.4	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.5	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.6	3	2	-	-	-	-	-	-	-	-	-	1	-	-
AVE	3	2	-	-	-	-	-	-	-	-	-	1	-	-



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### MAPPING OF EXPERIMENT OUTCOMES WITH CO/PO'S/PSO

EXPERIMENT	EXPERIMENT		
OBJECTIVES	OUTCOMES	CO	PO'S
To determine the work function "φ" of a metal.	The student determines the work function in a given material using photoelectric effect	C126.1	PO1,PO2, PO12
To determine the Hall voltage developed across the sample material.     To calculate the Hall coefficient and the carrier concentration of the sample material	The student determines the hall voltage across the given sample and calculates the hall coefficient	C126.2	PO1,PO2,PO12
To study the frequency response and to find resonant frequencies of L-C-R series and parallel Circuits.	The student studies the frequence and to find resonant frequencie of L-C-R series and parallel Circuits.	C126.4	PO1,PO2,PO12
To draw the characteristics of p-r Zener diode	The student draws the characteric junction and Zener diodes	C126.3	PO1,PO2,PO12
Observe the i/p and o/p character Of BJT(CE,CB and CC)	The student observe the characte BJT(CE,CB and CC)	C126.3	PO1,PO2,PO12
1.To Plot the V/I characteristics of Solar Cell  2.To study the volt-ampere characteristics of a given LED source	The student can able to plot the V/I characteristics of Solar Cell, LED	C126.3	PO1,PO2,PO12
To determine the energy gap of a junction diode	The student will be able to evaluate the energy gap between two allowed bands for isolated atoms and recognizing the resistivity of semiconductor varies with temperature.	C126.2	PO1, PO2,PO12
To determine the resistivity of semiconductor by two probe method	The student will determine the resistivity of semiconductor by two probe method	C126.2	PO1,PO2,PO12

To study B-H of a magnetic material	The student will study B-H of a magnetic material	C126.6	PO1,PO2,PO12
To determine the dielectric constant of a given material	The student will determine the dielectric constant	C126.6	PO1,PO2,PO12
To determine the beam divergence of the given LASER beam and Numerical Aperture of an optical fiber	The student will determines the wave length of laser source using single slit diffraction grating.	C126.5	PO1,PO2,PO12
Understanding the method of Least squares – torsional pendulu	The student Understanding the r Least squares – torsional pendul	C126.6	PO1,PO2,PO12
To study the Charging and Discharging of a Capacitor	The student studies the Charging and Discharging of a Capacitor/Condenser	C126.5	PO1,PO2,PO12



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**Class: DATA SCIENCE** 

<u>Semester</u>: II <u>W.E.F</u>-03-04-2023

LH: D-208

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MON		PYTHON LAI	3		AP	ODE	EDC	LIBRARY
TUE	]	ITWS/EWS LA	L U	AP	EDC	ODE(T) /AP(T)		
WED	ODE	AP	ES	N C	ITWS/EWS LAB			PYTHON LAB(T)/ EWS(T)
THU	ODE	ENG	EDC	Н	ODE	EDC	AP	AP(T)/ODE(T)
FRI	AP	ENG	EDC		AP/ELCS LAB			EWS(T)/ PYTHONLAB(
SAT	ENG	ODE	ES		AP/ELCS LAB			ES

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AP202BS	AP-Applied Physics	Dr.B.NAGALAKSHMI	CS201ES	Pytnon Programming Laboratory	P.BALU/M.TEJAS WI
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EC201ES	EDC-Electronics Devices and Circuits	P.SUMANA	CS203ES	ITWS-IT Workshop	B.RAJITHA/N.KEE RTHI CHANDANA
ME202ES	EWS-Engineering Workshop	W.MARUTHI/B.SRIN U NAIK	MC201ES	ES-Environmental Science	G.VIJAY

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Head of The Department

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### **AP Lab External Question Paper**

<ol> <li>Determine the work function of given metal by using photoelectric effect.</li> <li>Derive the values of i) Resonance Frequency ii) Band width iii) Quality Factor of the given LCR</li> <li>Plot the V –I Characteristics of LED.</li> <li>Determine the energy gap of a given semiconductor.</li> <li>Determine the dielectric constant of a given material.</li> <li>Determine the beam divergence of the given LASER light.</li> <li>Determine the acceptance angle and numerical aperture of an optical fiber.</li> <li>Find Hall coefficient and carrier concentration of a given semiconductor.</li> <li>Draw the V-I characteristics of P-N junction diode</li> <li>Plot the V –I Characteristics of Zener diode.</li> </ol>		: 2022-23 ΓΕ: 24-08-23(FN)		SEM-II	Branch: CSE (DATA SCIENCE)
<ol> <li>Derive the values of i) Resonance Frequency ii) Band width iii) Quality Factor of the given LCR</li> <li>Plot the V –I Characteristics of LED.</li> <li>Determine the energy gap of a given semiconductor.</li> <li>Determine the dielectric constant of a given material.</li> <li>Determine the beam divergence of the given LASER light.</li> <li>Determine the acceptance angle and numerical aperture of an optical fiber.</li> <li>Find Hall coefficient and carrier concentration of a given semiconductor.</li> <li>Draw the V-I characteristics of P-N junction diode</li> </ol>	DΛ	TE. 24-00-25(FIV)			
<ol> <li>Plot the V -I Characteristics of LED.</li> <li>Determine the energy gap of a given semiconductor.</li> <li>Determine the dielectric constant of a given material.</li> <li>Determine the beam divergence of the given LASER light.</li> <li>Determine the acceptance angle and numerical aperture of an optical fiber.</li> <li>Find Hall coefficient and carrier concentration of a given semiconductor.</li> <li>Draw the V-I characteristics of P-N junction diode</li> </ol>	1.	Determine the work	κ function of given n	netal by using photoele	ectric effect.
<ol> <li>Determine the energy gap of a given semiconductor.</li> <li>Determine the dielectric constant of a given material.</li> <li>Determine the beam divergence of the given LASER light.</li> <li>Determine the acceptance angle and numerical aperture of an optical fiber.</li> <li>Find Hall coefficient and carrier concentration of a given semiconductor.</li> <li>Draw the V-I characteristics of P-N junction diode</li> </ol>	2.	Derive the values	of i) Resonance Frec	quency ii) Band width i	iii) Quality Factor of the given LCR circuit.
<ol> <li>Determine the dielectric constant of a given material.</li> <li>Determine the beam divergence of the given LASER light.</li> <li>Determine the acceptance angle and numerical aperture of an optical fiber.</li> <li>Find Hall coefficient and carrier concentration of a given semiconductor.</li> <li>Draw the V-I characteristics of P-N junction diode</li> </ol>	3.	Plot the V –I Charac	teristics of LED.		
<ul> <li>6. Determine the beam divergence of the given LASER light.</li> <li>7. Determine the acceptance angle and numerical aperture of an optical fiber.</li> <li>8. Find Hall coefficient and carrier concentration of a given semiconductor.</li> <li>9. Draw the V-I characteristics of P-N junction diode</li> </ul>	4.	Determine the ener	gy gap of a given sei	niconductor.	
<ul> <li>7. Determine the acceptance angle and numerical aperture of an optical fiber.</li> <li>8. Find Hall coefficient and carrier concentration of a given semiconductor.</li> <li>9. Draw the V-I characteristics of P-N junction diode</li> </ul>	5.	Determine the diele	ectric constant of a g	iven material.	
<ul><li>8. Find Hall coefficient and carrier concentration of a given semiconductor.</li><li>9. Draw the V-I characteristics of P-N junction diode</li></ul>	6.	Determine the bean	n divergence of the §	given LASER light.	
9. Draw the V-I characteristics of P-N junction diode	7.	Determine the acce	ptance angle and nu	merical aperture of an	optical fiber.
	8.	Find Hall coefficient	t and carrier concen	tration of a given semi	iconductor.
10. Plot the V –I Characteristics of Zener diode.	9.	Draw the V-I charac	cteristics of P-N junc	tion diode	
	10	. Plot the V –I Charac	teristics of Zener di	ode.	

11. Plot the V -I Characteristics of solar cell.



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# AP Lab External Time Table Examination Branch

A.Y.: 2022-23 SEM-II

DATE	Day	Branch	Session	HT.No	Total No of Students
19-08-23	SATURDAY	CSE-C	AN	22X31A05D1 TO 22X31A05J1	61
21-08-23	MONDAY	CSE-B	AN	22X31A0566 TO 22X31A05D0	65
22-08-23	TUESDAY	CS	FN	22X31A6201 TO 22X31A6262	62
23-08-23	WEDNESDAY	DS	FN	22X31A6701 TO 22X31A6764	62
24-08-23	THURSDAY	CSE-A	FN	22X31A0501 TO 22X31A0565	65

FN: 9.40 am to 12.25 pm AN: 1.00 pm to 4.00 pm

Head of the Department
Department of H&S
SRI INDU INSTITUTE OF ENGG & TECH

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### **AP Lab External Time Table with examiners**

A.Y.: 2022-23 SEM-II

					Total	R	emarks
Date	Day	Branch	Sessio n	HT.No	No of Stude nts	Internal Examiner	External Examiner
19-08-23	SATURDAY	CSE-C	AN	22X31A05D1 TO 22X31A05J1	61	B. SANTHI (9493978954)	Dr. B. Narsimha (9490356088)
21-08-23	MONDAY	CSE-B	AN	22X31A0566 TO 22X31A05D0	65	M.JANAIAH (9291513934)	Mrs. G. Sandhya (9441719540)
22-08-23	TUESDAY	CS	FN	22X31A6201 TO 22X31A6262	62	B.SANTHI (9493978954)	Dr. A. Azhagiri (9952583969)
23-08-23	WEDNESDA Y	DS	FN	22X31A6701 TO 22X31A6764	62	M.JANAIAH (9291513934)	Mr. P. Venkatesh- (9014229680)
24-08-23	THURSDAY	CSE-A	FN	22X31A0501 TO 22X31A0565	65	P.SRINIVAS A CAHARY (9848662600)	Dr.B.Rajini Kanth (7893092879)

FN: 9.40 am to 12.25 pm AN: 1.00 pm to 4.00 pm

Head of the Department
Department of H&S

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### DEPARTMENT OF HUMANITIES AND SCIENCES

### **Lab Occupancy Time Table for AY 2022-2023**

Class: IB. Tech Semester: II W.E.F-03-04-2023 LH: B-201

D 1 1/	1	2	3	12:10- 12:45	4	5	6	7
Period/ Day	9:40- 10:30	10:30-11:20	10:30-11:20 11:20- 12:10		12.45-1.35	1:35- 2.25	2:25- 3:15	3:15-4:00
Monday						•		
Tuesday	CSE-B	(BATCH-II)		L				
Wednesday				U N C	CSE	I-II)		
Thursday	M	AINTANANCE	E	Н				
Friday	CS	E-A (BATCH-I	I)		DATA S	CIENCE(BA	ATCH-1)	
Saturday	CYBER S	SECURITY(BA	TCH-II)		DATA S	CIENCE(BA	TCH-1I)	

Head of the Department
Department of H&S
SRI INDU INSTITUTE OF ENGG & TECH
Periouda(\(^\) Ibrahimoatnam (\(^\)) R.R. Dist-501 516

PRINCIPAL
Sri Indu Institute of Engineering & Tech
Sheriguda(Vill), Ibrahimpatnam
R.R. Dist. Telangana-501 510.



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(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501510

https://siiet.ac.in/

### DEPARTMENT OF HUMANITIES AND SCIENCES

### **Lab Occupancy Time Table for AY 2022-2023**

Class: IB. Tech Semester: II W.E.F- 03-04-2023 LH: D-106

	1	2	3		4	5	6	7
Period/ Day	9:40- 10:30	10:30- 11:20	11:20- 12:10	1 2: 1 ()-	12.45- 1.35	1:35- 2.25	2:25- 3:15	3:15- 4:00
Monday	CSE-C (B	BATCH-I)			CSE			
Tuesday					MAINTANANCE			
Wednesday								
Thursday	CSE-	A(BATCH-	-I)					
Friday					CYBER SI	ECURITY(I	BATCH-I)	
Saturday								

Head of the Department
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Website: https://siiet.ac.in/

### APPLIED PHYSICS LAB

Course: B.Tech. I Year SUB CODE: AP205BS

### Do's

- 1. Conduct in a responsible manner at all times in the laboratory.
- 2. Keep the work area clean, neat and free of any unnecessary objects.
- 3. Read the description, procedure and precautions of the experiment in the lab manual.
- 4. Place all sensitive electronic equipment safely on experimental table.
- 5. Before using the equipment one must read the labels and instructions carefully.
- 6. Set up and use the equipment as directed by the lab instructor.
- 7. Circuit connections are to be done only in power off mode.
- 8. Checkout the circuit connections before switching on the power.
- 9. Increase the power readings from minimum to maximum.
- 10. All procedures and experimental data should be recorded in the lab observation notebook.
- 11. Switch of the power in the circuit after completion of the experiment.
- 12. Any failure / break-down of equipment must be reported to the instructor.
- 13. Return the material properly after the completing the experiment.
- 14. Replace the materials in proper place after work.
- 15. Be careful when handling optical items like prisms, gratings etc.

### Don't s

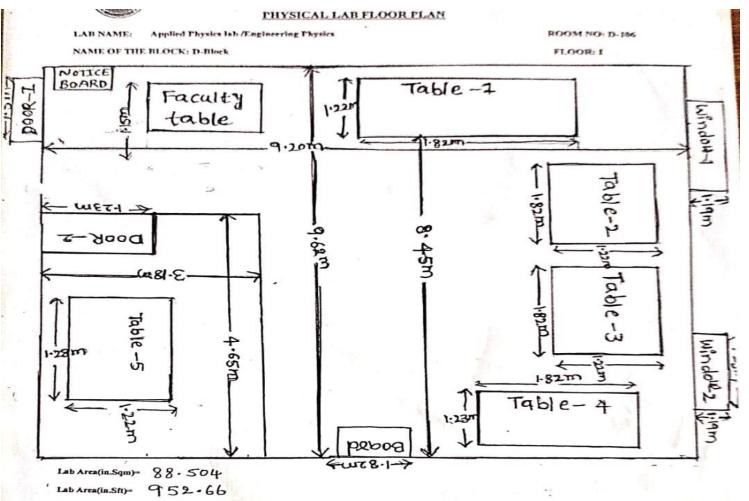
- 1. Do not wear loose clothing and do not hold any conducting materials in contact with skin when the power is on.
- 2. Do not touch any equipment or other materials in the laboratory area until instructed by instructor.
- 3. Do not modify or damage the laboratory equipment in any way unless the modification is directed by the instructor.
- 4. Do not handle electrical equipment and connections with wet hands.
- 5. Do not try to connect power in to the circuit without proper understanding of the circuit diagram.
- 6. Do not look directly into laser source.
- 7. Do not short any battery box or power supply, it may damage retina in your eye.
- 8. Never switch on the power button of the circuit until it has been approved by instructor.



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Website: https://siiet.ac.in/

### APPLIED PHYSICS LAB - 1 FLOOR PLAN



Lab In charge

Head of the Department

Jan /





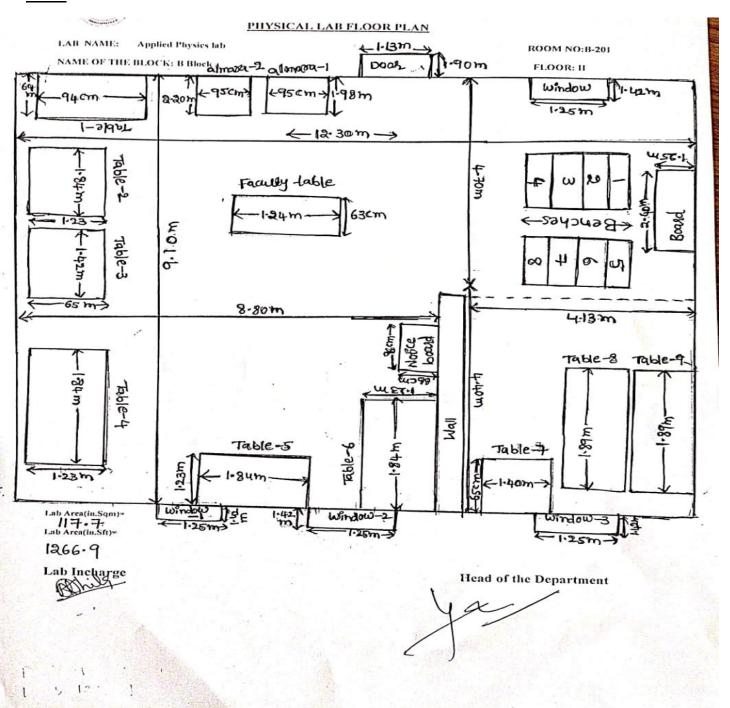
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### **APPLIED PHYSICS LAB - 2FLOOR**

### **PLAN**



510



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Website: https://siiet.ac.in/

### Lab manual link

https://drive.google.com/file/d/1UTyWcm6bNeIw5qa 7CrdjE7PxMdQmHJ/view?usp=s haring

### SRI INDU INSTITUTE OF ENGINEERING AND TECHNOLOGY Department of Humanities and Sciences Course Outcome Attainment (Internal Examination-1) Name of the faculty: M.JANAIAH Academic Year: 2022 - 23 DATA SCIENCE LAB INTERNAL-I Branch & Section: Examination: Lab Course Name: APPLIED PHYSICS Year/semester E+E+RS.No HT No. R+O+AV+VMax. Marks ==> 22X31A6701 22X31A6702 22X31A6703 22X31A6704 O 22X31A6705 22X31A6706 22X31A6707 22X31A6708 22X31A6709 22X31A6710 22X31A6711 22X31A6712 22X31A6713 22X31A6714 22X31A6715 22X31A6716 22X31A6717 22X<u>31A6718</u> 22X31A6719 22X31A6720 22X31A6721 22X31A6722 22X31A6723 22X31A6724 22X31A6725 22X31A6726 22X31A6727 22X31A6728 22X31A6729 22X31A6730 Q O 22X31A6731 22X31A6732 22X31A6733 Ω 22X31A6734 22X31A6735 22X31A6736 Q 22X31A6737 22X31A6738 22X31A6739 22X31A6740 22X31A6741 22X31A6742 22X31A6743 22X31A6744 22X31A6745 22X31A6746 22X31A6747 22X31A6748 22X31A6749 22X31A6750 22X31A6751 22X31A6752 22X31A6753 22X31A6754 22X31A6755 22X31A6756 22X31A6757 22X31A6758 22X31A6759 22X31A6760 Q O 22X31A6761 22X31A6762 22X31A6763

22X31A6764

Target set by the faculty / HoD	6.00	6.00	6.00			
Number of students performed above the target	60	57	60			
Number of students attempted	62	62	62			
Percentage of students scored more than target	97%	92%	97%			
CO Mapping with Exam Qu	estions:					
CO - 1	y	y	Y			
CO - 2	y	$\mathbf{y}$	Y			
CO - 3	y	y	Y			
CO - 4		-				
CO - 5						
CO - 6						
CO Attainment based on Ex	am Questions:					
CO - 1	97%	97%	97%			
CO - 2	97%	97%	97%			
CO - 3	97%	97%	97%			
CO - 4						
CO - 5						
CO - 6						
со	Intrnal practical	E+E+R	OveralI	Level		
CO-1	97%	97%	97%	3		
CO-2	97%	97%	97%	3	Attainn	nent Level
CO-3	97%	97%	97%	3	1	40%
CO-4					2	50%
CO-5					3	60%
CO-6	†					
	(Internal 1 Ex	amination	) =	3		

Target set by the faculty / HoD	6.00	6.00	6.00	6.00			
Number of students performed above the target	59	44	55	0			
Number of students attempted	62	62	62	0			
Percentage of students scored more than target	95%	71%	89%				
CO Mapping with Exam Ques	tions:						
GO 1							
CO - 1							
CO - 2							
CO - 3 CO - 4			V				
CO - 4 CO - 5	у	<u>y</u>	Y	y y			
CO - 6	y	y	Y	V			
	3	J	-	J			
CO Attainment based on Exar	m Questions:						
CO - 1							
CO - 2							
CO - 3							
CO - 4	95%	71%	89%	89%			
CO - 5	95%	71%	89%	89%			
CO - 6	95%	71%	89%	89%			
СО	Intrnal practical	E+E+R	ppt	OveralI	Level		
CO-1	_						
CO-2							
CO-3							
CO-4	83%	89%	89%	87%	3	Attainment 1	Level
CO-5	83%	89%	89%	87%	3	1	40%
CO-6	83%	89%	89%	87%	3	2	50%
Attainment (I			_		3	3	60%
1 Manificile (1	$a_{11}$ Critat $\angle a_{12}$	ammanoi	1) —		3	)	00%

Department of Humanities and Sciences

### Course Outcome Attainment (Internal Examination-2)

Name of the faculty: M. JANAIAH Academic Year: 2022 - 23
Branch & Section: DATA SCIENCE Examination: LAB INTERNAL-II

Lab Course Name: APPLIED PHYSICS Year/semester I/II

Lab Co	burse Name:	APPLIED PHYSIC	<u></u>	r ear/semester	1/11
S.No	HT No.	R+O+A	V+V	E+E+R	ppt
Max. Ma	rks ==>	10	10	10	10
1	22X31A6701	9	6	8	10
2	22X31A6702	10	3	7	10
3		10	9	10	10
	22X31A6703	10	9	10	10
4	22X31A6704				
5	22X31A6705	9	6	6	10
6	22X31A6706	9	6	8	10
7	22X31A6707	9	5	8	10
8	22X31A6708	9	3	7	10
9	22X31A6709	9	8	9	10
10	22X31A6710	10	6	8	10
11	22X31A6710 22X31A6711	10	8	10	10
12		9	2	5	10
	22X31A6712	9	6	8	10
13	22X31A6713				
14	22X31A6714	8	7	7	10
15	22X31A6715	10	9	10	10
16	22X31A6716	10	2	6	10
17	22X31A6717	10	5	5	10
18	22X31A6718	10	10	10	10
19	22X31A6719	10	8	8	10
20		9	8	9	10
	22X31A6720	10	8	8	10
21	22X31A6721				
22	22X31A6722	10	3	8	10
23	22X31A6723	10	5	8	10
24	22X31A6724	10	10	6	10
25	22X31A6725	10	6	8	10
26	22X31A6726	10	8	10	10
27		8	10	9	10
	22X31A6727	10	7	8	10
28	22X31A6728	7			10
29	22X31A6729		6	8	
30	22X31A6730	10	4	8	10
31	22X31A6731	10	7	10	10
32	22X31A6732				10
33	22X31A6733	10	7	9	10
34	22X31A6734	9	9	8	10
35	22X31A6735				10
36		10	7	10	10
	22X31A6736	10	6	9	10
37	22X31A6737				
38	22X31A6738	10	6	10	10
39	22X31A6739	4	4	6	10
40	22X31A6740	4	5	5	10
41	22X31A6741	5	4	5	10
42	22X31A6742	6	6	8	10
43	22X31A6743	9	8	8	10
44	22X31A6744	10	8	8	10
45		10	10	10	10
	22X31A6745	8	5	10	10
46	22X31A6746				
47	22X31A6747	10	7	10	10
48	22X31A6748	9	6	10	10
49	22X31A6749	8	8	8	10
50	22X31A6750	8	7	9	10
51	22X31A6751	9	7	10	10
52	22X31A6752	9	2	5	10
53		6	4	5	10
	22X31A6753				
54	22X31A6754	9	9	8	10
55	22X31A6755	9	6	8	10
56	22X31A6756	6	6	6	10
57	22X31A6757	8	2	7	10
58	22X31A6758	6	6	9	10
59	22X31A6759	10	7	10	10
60	22X31A6760	10	5	9	10
61		7	6	8	10
	22X31A6761	7	5	5	
62	22X31A6762				10
63	22X31A6763	8	9	8	10
64	22X31A6764	10	8	10	10
		į į			1
	1	·		<u> </u>	

Target set by the faculty / HoD	6.00	6.00	6.00	6.00			
Number of students performed above the target	59	44	55	64			
Number of students attempted	62	62	62	64			
Percentage of students scored more than target	95%	71%	89%	100%			
CO Mapping with Exam Que	estions:						
CO - 1							
CO - 2							
CO - 3							
CO - 4	Y	Y	Y	Y			
CO - 5	Y	Y	Y	Y			
CO - 6	Y	Y	Y	Y			
CO Attainment based on Exa	nm Questions:						
CO - 1							
CO - 2							
CO - 3							
CO - 4	95%	71%	89%	89%			
CO - 5	95%	71%	89%	89%			
CO - 6	95%	71%	89%	89%			
СО	Intrnal practical	E+E+R	ppt	OveralI	Level	Ī.	
CO-1							
CO-2							
CO-3							
CO-4	83%	89%	89%	87%	3	Attainment I	evel
CO-5	83%	89%	89%	87%	3	1	40%
CO-6	83%	89%	89%	87%	3	2	50%
Attainment (	Internal 2 Ex	aminatior	n) =		3	3	60%

Department of Humanities and Sciences

**Course Outcome Attainment (University Examinations)** Name of the faculty: Academic Year: **M.JANAIAH** 2022 - 23 Branch & Section: DATA SCIENCE Year / Semester: I/II APPLIED PHYSICS Lab Course Name: S.No **Roll Number** Marks Secured S.No **Roll Number** Marks Secured 22X31A6701 22X31A6736 34 41 55 2 22X31A6702 35 22X31A6737 38 53 22X31A6703 22X31A6738 3 36 58 54 4 22X31A6704 58 37 22X31A6739 38 5 38 22X31A6740 22X31A6705 50 27 39 6 22X31A6706 35 22X31A6741 28 7 22X31A6707 22X31A6742 40 49 35 41 8 22X31A6708 22X31A6743 50 33 22X31A6744 9 22X31A6709 40 42 52 22X31A6710 43 10 44 22X31A6745 58 11 22X31A6711 52 44 22X31A6746 42 45 12 22X31A6712 22X31A6747 38 58 13 22X31A6713 35 46 22X31A6748 53 14 22X31A6714 47 22X31A6749 41 42 15 22X31A6715 48 22X31A6750 58 55 16 22X31A6716 49 22X31A6751 40 56 17 22X31A6717 50 22X31A6752 50 30 22X31A6718 51 22X31A6753 18 58 29 22X31A6719 52 22X31A6754 19 43 56 20 22X31A6720 22X31A6755 42 53 33 22X31A6721 22X31A6756 21 54 51 27 22X31A6722 22X31A6757 22 52 55 28 23 22X31A6723 56 22X31A6758 45 29 24 22X31A6724 48 57 22X31A6759 55 25 22X31A6725 58 22X31A6760 51 48 26 22X31A6726 59 22X31A6761 58 38 27 22X31A6727 22X31A6762 60 51 40 28 22X31A6728 49 61 22X31A6763 51 29 22X31A6764 22X31A6729 62 31 52 30 22X31A6730 41 31 22X31A6731 52 32 22X31A6733 57 33 22X31A6734 52 Attainment Level | % students Class Average mark 45 Number of students performed above the target 33 40% Number of successful students 62 2 50% Percentage of students scored more than target 53% 3 60% Attainment level 3

THE OF EAGUES AND ASSESSED ASSESSEDA	Departme					
ALLANA SALANA		Course Ou	itcome A	<u>ttainment</u>		
Макрати						
Name of the faculty				Academic Year:		
Branch & Section:	DATA SO			Year / Semester:	I/II	
Lab Course Name:	APPLIED I	PHYSICS				
Course Outcomes	1st Internal Exam	2nd Internal Exam	Internal Exam	University Exam	Attainment Level	
CO1	3.00		3.00	3.00	3.00	
CO2	3.00		3.00	3.00	3.00	
CO3	3.00		3.00	3.00	3.00	
CO4		3.00	3.00	3.00	3.00	
CO5		3.00	3.00	3.00	3.00	
CO6		3.00	3.00	3.00	3.00	
Inter	nal & Unive	ersity Attainment:	3.00	3.00		
		Weightage	70%	30%		
CO Attainment for the	e course (Int	ternal, University)	2.10	0.90		
CO Attainment for	the course (	Direct Method)		3.00		
Overall co	urse a	ıttainmer	ıt leve	el	3.00	

### SRI INDU INSTITUTE OF ENGINEERING & TECHNOLOGY Department of Humanities and Sciences **Program Outcome Attainment (from Course)** Academic Year: 2022 - 23 Name of Faculty: M. JANAIAH Branch & Section: **DATA SCIENCE** Year / Semester: I/II Course Name: APPLIED PHYSICS **CO-PO mapping** PO1 PO2 PO3 PO4 PO5 PO8 | PO9 | PO10 | PO11 | PO12 | PSO1 PO6 PO7 PSO<sub>2</sub> 3 2 CO1 3 2 CO2 1 3 2 1 CO3 3 2 CO4 3 1 2 CO5 2 CO6 3 Course |3.00| 2.00 1.00 **Course Outcome Attainment** CO 3.00 CO1 3.00 CO2 3.00 CO3 3.00 CO4 3.00 **CO5** 3.00 **CO6** Overall course attainment level 3.00 **PO-ATTAINMENT** PO1 PO2 PO3 PO4 PO5 PO6 PO7 PO8 | PO9 | PO10 | PO11 | PO12 co Attainm 3.00 2.00 ent 1.00 CO contribution to PO - 33%, 67%, 100% (Level 1/2/3)